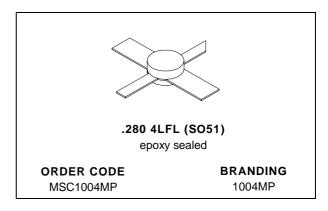


MSC1004MP

RF & MICROWAVE TRANSISTORS AVIONICS APPLICATIONS

- 1025 1150 MHz
- RUGGEDIZED VSWR ∞:1
- INTERNAL INPUT MATCHING
- LOW THERMAL RESISTANCE
- $P_{OUT} = 4.0 \text{ W MIN. WITH } 9.0 \text{ dB GAIN}$

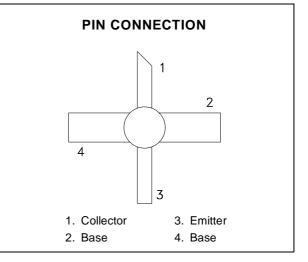


DESCRIPTION

The MSC1004MP is a low-level Class C pulsed transistor specifically designed for DME/IFF driver or output applications.

These devices are capable of withstanding a ∞ :1 load VSWR at any phase angle under full rated conditions. Low RF thermal resistance and automatic bonding techniques ensure high reliability and product consistency.

The MSC1004MP is housed in the IMPAC^{\rm TM} package with internal input matching.



ABSOLUTE MAXIMUM RATINGS $(T_{case} = 25^{\circ}C)$

Symbol	Parameter	Value	Unit
P _{DISS}	Power Dissipation [*] $(T_C \le 100^{\circ}C)$	18	W
Ι _C	Device Current*	650	mA
Vcc	Collector-Supply Voltage*	32	V
TJ	Junction Temperature	200	°C
T _{STG}	Storage Temperature	– 65 to +150	°C

THERMAL DATA

R _{TH(j-c)}	Junction-Case Thermal Resistance*	5	°C/W
*Applies only to rated RF amplifier operation			

June 12, 1995

ELECTRICAL SPECIFICATIONS ($T_{case} = 25^{\circ}C$)

Symbol	Test Conditions	Value			11:1:4		
		Min.	Тур.	Max.	Unit		
ВVсво	$I_C = 1 \text{ mA}$	$I_E = 0 mA$		45	—	—	V
BVCER	$I_C = 5 \text{ mA}$	$R_{BE} = 10 \ \Omega$		45	—	—	V
BV_{EBO}	$I_E = 1 \text{ mA}$	$I_C = 0 m A$		3.5	—	—	V
I _{CES}	$V_{CE} = 28 V$				—	1.0	mA
h _{FE}	$V_{CE} = 5 V$	I _C = 200 mA		30	_	300	_

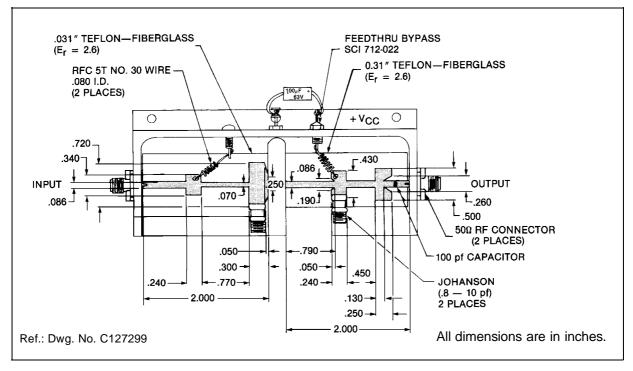
STATIC

DYNAMIC

Symbol	Test Conditions			Value		Unit	
Symbol				Min.	Тур.	Max.	Unit
POUT	f = 1025 - 1150 MHz	$P_{\text{IN}} = 500 \text{ mW}$	$V_{CC}=28\ V$	4.0		—	W
ηc	f = 1025 - 1150 MHz	$P_{IN} = 500 \text{ mW}$	$V_{CC} = 28 V$	35			%
GP	f = 1025 - 1150 MHz	$P_{IN}=500\ mW$	$V_{CC}=28\ V$	9.0	—		dB

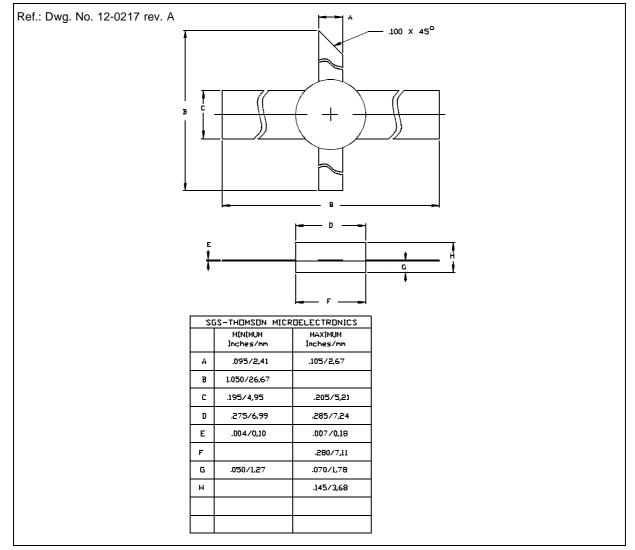
Note: Pulse Width = 10μ Sec Duty Cycle = 1%

TEST CIRCUIT





PACKAGE MECHANICAL DATA



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June 12, 1995

